TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX273F,TC74LVX273FW,TC74LVX273FT

Octal D-Type Flip-Flop with Clear

The TC74LVX273F/ FW/ FT is a high-speed CMOS octal D-flip flop fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

Information signals applied to D inputs are transferred to the Q outputs on the positive going edge of the clock pulse. When the \overline{CLR} input is held low, the Q outputs are in the low logic level independent of the other inputs.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

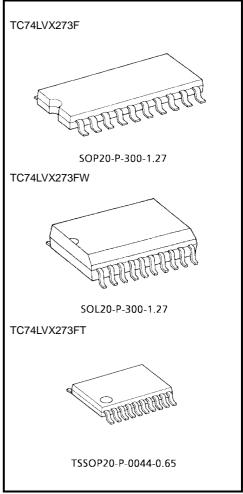
Features

- High-speed: $f_{max} = 150 \text{ MHz (typ.) (VCC} = 3 \text{ V)}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- Input voltage level: $V_{IL} = 0.8 \text{ V (max)} (V_{CC} = 3 \text{ V})$

 $V_{IH} = 2.0 \text{ V (min) (V}_{CC} = 3 \text{ V)}$

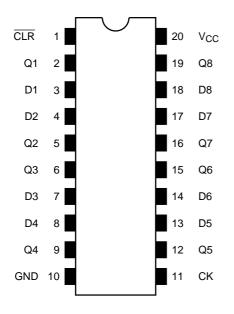
- Power-down protection provided on all inputs
- Balanced propagation delays: t_{pLH} ≈ t_{pHL}
- Low niose: VOLP = 0.8 V (max)
- Pin and function compatible with 74HC273

Note: xxxFW (JEDEC SOP) is not available in Japan.

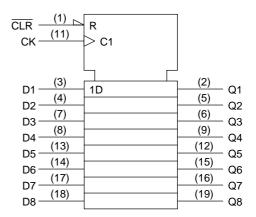


Weight SOP20-P-300-1.27: 0.22 g (typ.) SOL20-P-300-1.27: 0.46 g (typ.) TSSOP20-P-0044-0.65: 0.08 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol

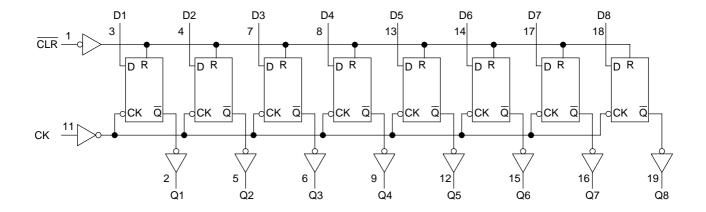


Truth Table

| | Inputs | | Outputs | Function |
|-----|--------|--------|---------|-----------|
| CLR | D | CK | Q | Tariction |
| L | Х | Х | L | Clear |
| Н | L | | L | _ |
| Н | Н | | Н | _ |
| Н | Х | \neg | Qn | No change |

X: Don't care

System Diagram





Maximum Ratings

| Characteristics | Symbol | Rating | Unit |
|------------------------------------|------------------|--------------------------|------|
| Supply voltage range | V _{CC} | -0.5 to 7.0 | V |
| DC input voltage | V _{IN} | -0.5 to 7.0 | V |
| DC output voltage | V _{OUT} | -0.5 to $V_{CC} + 0.5$ | V |
| Input diode current | I _{IK} | -20 | mA |
| Output diode current | lok | ±20 | mA |
| DC output current | lout | ±25 | mA |
| DC V _{CC} /ground current | I _{CC} | ±75 | mA |
| Power dissipation | PD | 180 | mW |
| Storage temperature | T _{stg} | -65 to 150 | °C |

Recommended Operating Conditions

| Characteristics | Symbol | Rating | Unit |
|--------------------------|------------------|----------------------|------|
| Supply voltage | V _{CC} | 2.0 to 3.6 | V |
| Input voltage | V _{IN} | 0 to 5.5 | V |
| Output voltage | V _{OUT} | 0 to V _{CC} | V |
| Operating temperature | T _{opr} | -40 to 85 | °C |
| Input rise and fall time | dt/dv | 0 to 100 | ns/V |

Electrical Characteristics

DC Characteristics

| Characteristics | | Sym- bol | | | | Ta = 25°C | | | Ta = -40 to 85°C | | Unit |
|--------------------------|-----------------------|-------------------------|---|--------------------------|-----|-----------|-----|------|---------------------|------|------|
| | | | | V _{CC} (V) | Min | Тур. | Max | Min | Max | | |
| | | | | _ | | 1.5 | _ | _ | 1.5 | _ | |
| | H-level | V _{IH} | | | | 2.0 | _ | _ | 2.0 | _ | |
| Input voltage | | | | | 3.6 | 2.4 | | | 2.4 | | V |
| input voltage | | | | | 2.0 | | | 0.5 | | 0.5 | v |
| | L-level | V_{IL} | _ | | 3.0 | _ | _ | 8.0 | _ | 0.8 | |
| | | | | | 3.6 | _ | _ | 0.8 | _ | 0.8 | |
| | | H-level V _{OH} | | $I_{OH} = -50 \ \mu A$ | 2.0 | 1.9 | 2.0 | _ | 1.9 | _ | |
| | H-level | | V _{IN} = V _{IH} or V _{IL} | $I_{OH} = -50 \ \mu A$ | 3.0 | 2.9 | 3.0 | | 2.9 | | |
| Output voltage | | | | $I_{OH} = -4 \text{ mA}$ | 3.0 | 2.58 | _ | | 2.48 | _ | V |
| Odiput voltage | | | | $I_{OL} = 50 \ \mu A$ | 2.0 | _ | 0 | 0.1 | _ | 0.1 | v |
| | L-level | V _{OL} | V _{IN} = V _{IH} or V _{IL} | $I_{OL} = 50 \ \mu A$ | 3.0 | _ | 0 | 0.1 | _ | 0.1 | |
| | | | | $I_{OL} = 4 \text{ mA}$ | 3.0 | _ | _ | 0.36 | _ | 0.44 | |
| Input leakage currer | Input leakage current | | V _{IN} = 5.5 V or GND | | 3.6 | | _ | ±0.1 | _ | ±1.0 | μА |
| Quiescent supply current | | Icc | $V_{IN} = V_{CC}$ | or GND | 3.6 | _ | _ | 4.0 | _ | 40.0 | μΑ |

3

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

| Characteristics | Symbol | nbol Test Condition | | Ta = 25°C | Ta = -40 to 85°C | Unit | |
|----------------------|--------------------|---------------------|---------------------|-----------|---------------------|------|--|
| | | | V _{CC} (V) | Limit | Limit | | |
| Minimum pulse width | t _{W (L)} | | 2.7 | 8.0 | 9.5 | ns | |
| (CK) | t _{W (H)} | <u>—</u> | 3.3 ± 0.3 | 5.5 | 6.5 | 113 | |
| Minimum pulse width | * | | 2.7 | 7.5 | 8.5 | ne | |
| (CLR) | t _{W (L)} | _ | 3.3 ± 0.3 | 5.0 | 6.0 | ns | |
| Malana and an Cara | t _S | | 2.7 | 8.0 | 9.5 | ns | |
| Minimum set-up time | | _ | 3.3 ± 0.3 | 5.5 | 6.5 | 115 | |
| Minimum hold time | t _h | | 2.7 | 1.0 | 1.0 | no | |
| Minimum noid time | | _ | 3.3 ± 0.3 | 1.0 | 1.0 | - ns | |
| Minimum removal time | | | 2.7 | 4.0 | 4.0 | ns | |
| (CLR) | t _{rem} | _ | 3.3 ± 0.3 | 2.5 | 2.5 | 115 | |

AC Characteristics (input: $t_r = t_f = 3$ ns)

| Characteristics | Symbol Test Condition | | | | Ta = 25°C | | | Ta = -40 to 85°C | | Unit |
|---------------------------------|-----------------------|----------|---------------------|---------------------|-----------|------|------|---------------------|------|-------|
| | | | V _{CC} (V) | C _L (pF) | Min | Тур. | Max | Min | Max | |
| | | | 2.7 | 15 | _ | 9.0 | 16.9 | 1.0 | 20.5 | |
| Propagation delay time | t _{pLH} | | 2.1 | 50 | _ | 11.5 | 20.4 | 1.0 | 24.0 | ns |
| (CK-Q) | . | _ | 3.3 ± 0.3 | 15 | _ | 7.1 | 11.0 | 1.0 | 13.0 | 113 |
| | t _{pHL} | | 3.3 ± 0.3 | 50 | _ | 9.6 | 14.5 | 1.0 | 16.5 | |
| | | | 2.7 | 15 | _ | 9.3 | 17.6 | 1.0 | 20.5 | - ns |
| Propagation delay time (CLR -Q) | t _{pHL} | _ | 2.7 | 50 | _ | 11.8 | 21.1 | 1.0 | 24.0 | |
| | | | 3.3 ± 0.3 | 15 | _ | 7.3 | 11.5 | 1.0 | 13.5 | |
| , , | | | | 50 | _ | 9.8 | 15.0 | 1.0 | 17.0 | |
| | f _{max} | | 2.7 | 15 | 55 | 110 | _ | 45 | _ | - MHz |
| Maximum alask fraguency | | | | 50 | 45 | 60 | _ | 40 | _ | |
| Maximum clock frequency | | _ | | 15 | 95 | 150 | _ | 80 | _ | |
| | | | 3.3 ± 0.3 | 50 | 60 | 90 | _ | 50 | _ | |
| Output to output alcow | t _{osLH} | (Note 1) | 2.7 | 50 | _ | _ | 1.5 | _ | 1.5 | no |
| Output to output skew | t _{osHL} | (Note 1) | 3.3 ± 0.3 | 50 | _ | _ | 1.5 | _ | 1.5 | ns |
| Input capacitance | C _{IN} | | | (Note 2) | | 4 | 10 | _ | 10 | pF |
| Power dissipation capacitance | C _{PD} | | | (Note 3) | _ | 31 | _ | _ | _ | pF |

Note 1: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$

Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per F/F)$

And the total C_{PD} when n pcs. of F/F operate can be gained by the following equation:

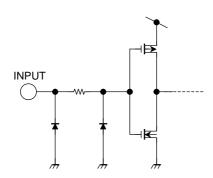
 C_{PD} (total) = 22 + 9 · n



Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, $C_L = 50$ pF)

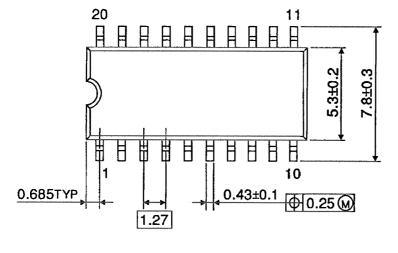
| Characteristics | | Symbol | Test Condition | V _{CC} (V) | Тур. | Limit | Unit |
|--|-----------------|------------------|----------------|---------------------|------|-------|------|
| Quiet output maximum dynamic | V_{OL} | V_{OLP} | _ | 3.3 | 0.5 | 0.8 | V |
| Quiet output minimum dynamic | V_{OL} | V_{OLV} | _ | 3.3 | -0.5 | -0.8 | V |
| Minimum high level dynamic input voltage | V _{IH} | V _{IHD} | _ | 3.3 | _ | 2.0 | V |
| Maximum low level dynamic input voltage | V _{IL} | V _{ILD} | | 3.3 | _ | 0.8 | V |

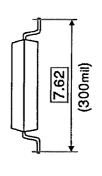
Input Equivalent Circuit

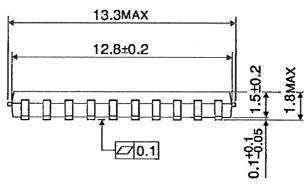


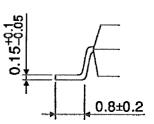
Package Dimensions

SOP20-P-300-1.27 Unit: mm







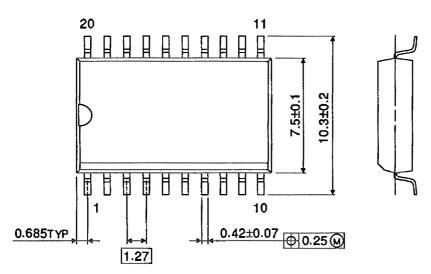


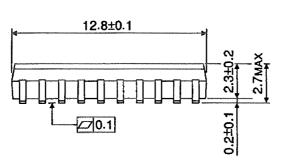
Weight: 0.22 g (typ.)

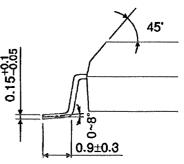
Unit: mm

Package Dimensions

SOL20-P-300-1.27





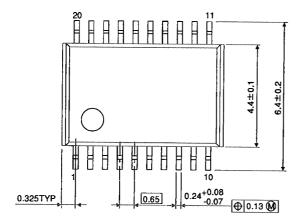


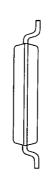
Weight: 0.46 g (typ.)

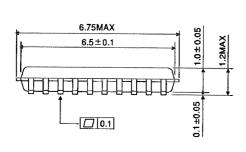
Unit: mm

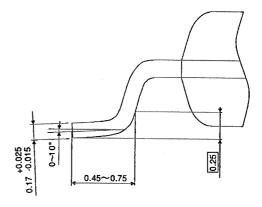
Package Dimensions

TSSOP20-P-0044-0.65









Weight: 0.08 g (typ.)

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